

CONNECTORIZED MODULE WIDEBAND MMIC VCO WITH BUFFER AMPLIFIER, 6GHz TO 9GHz

Package: Module, 3 Connectors, 22.86mmx22.86mmx13.97mm



Features

- 6GHz to 9GHz VCO
- 5V Operation, 53mA
- +3.5dBm Typical Output Power
- -73dBc/Hz @ 10kHz
- -97 dBc/Hz @ 100 kHz

Applications

- Military Radar, Communications, ECM/IED
- Satcomm Communication Modems
- Test Instrumentation
- Industrial/Medical Equipment



Functional Block Diagram

Product Description

RFMD's RFVC1803C wideband Voltage Controlled Oscillator is an InGaP HBT MMIC with integrated VCO core and RF output buffer. The part operates from a single +5V supply for circuit bias and 0V to +15V V_{TUNE} for frequency control. The RFVC1803C offers low phase noise and low power consumption.

Ordering Information

RFVC1803C C

Connectorized VCO

Optimum Technology Matching® Applied

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☐ GaAs HBT ☐ GaAs MESFET ☑ InGaP HBT

support, contact R

SiGe BiCMOS
Si BiCMOS
SiGe HBT

□ GaAs pHEMT □ GaN HEMT □ Si CMOS □ BiFET HBT □ Si BJT □ LDMOS

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Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{CC})	5.5	V
V _{TUNE}	0 to +20	V
Storage Temperature	-55 to +125	°C
Operating Temperature	-40 to +85	°C
ESD Rating – Human Body Model (HBM)	Class0	



Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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Parameter	Specification		Unit	Condition	
	Min.	Тур.	Max.	Unit	Condition
Frequency					
Frequency Range	6.0		9.0	GHz	
Supply Voltage (V _S)	4.75	5.00	5.25	V	Recommended operating range.
Supply Current	40	53	70	mA	
Tuning Voltage (V _{TUNE})	0		15	V	
Tuning Sensitivity		380		MHz/V	
Output Power		3.5		dBm	
Output Phase Noise at 10kHz		-73		dBc/Hz	
Output Phase Noise at 100 kHz		-97		dBc/Hz	
2nd Harmonic		-20		dBc	
Frequency Pushing		24		MHz/V	
Frequency Pulling (2:1 VSWR)		2.5		MHz pp	
RF Output Return Loss		-10		dB	
Frequency Drift Rate		-0.8		MHz/°C	
V _{TUNE} port input capacitance		7		pF	

Test Conditions: V_S =5V, Freq=6GHz to 9GHz, T=25 °C unless noted otherwise







RFVC1803C Thermal Performance versus Tuning Voltage



RFVC1803C Thermal Performance versus Frequency







Pin Out and Package Drawing (mm)



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